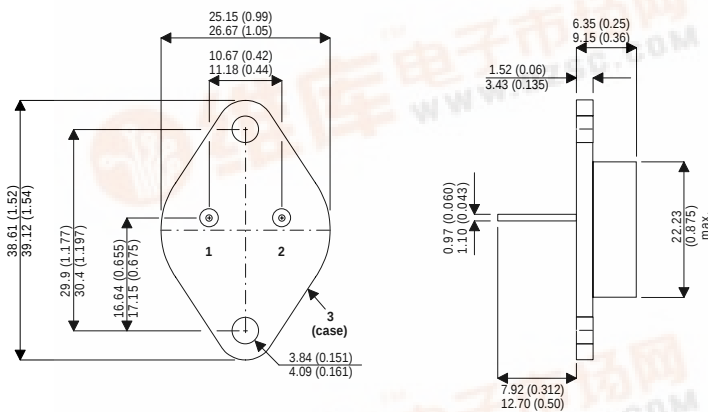


BUX10X

MECHANICAL DATA

Dimensions in mm(inches)

**TO-3**

PIN 1 — Base

PIN 2 — Emitter

Case is Collector.

**NPN MULTI - EPITAXIAL
POWER TRANSISTOR****FEATURES**

- HIGH CURRENT
- FAST SWITCHING
- HIGH RELIABILITY

APPLICATIONS

- POWER SWITCHING CIRCUITS
- MOTOR CONTROL

ABSOLUTE MAXIMUM RATINGS ($T_{\text{case}} = 25^{\circ}\text{C}$ unless otherwise stated)

V_{CBO}	Collector – Base Voltage ($I_{\text{E}} = 0$)	160V
V_{CEX}	Collector – Emitter Voltage ($V_{\text{BE}} = -1.5\text{V}$)	160V
V_{CEO}	Collector – Emitter Voltage ($I_{\text{B}} = 0$)	125V
V_{EBO}	Emitter – Base Voltage ($I_{\text{C}} = 0$)	7V
I_{C}	Collector Current	25A
I_{CM}	Peak Collector Current ($t_{\text{p}} = 10 \text{ ms}$)	30A
I_{B}	Base Current	5A
P_{tot}	Total Power Dissipation at $T_{\text{case}} \leq 25^{\circ}\text{C}$	150W
T_{stg}	Storage Temperature	-65 to 200°C
	Junction Temperature	200°C



ELECTRICAL CHARACTERISTICS ($T_{case} = 25^{\circ}C$ unless otherwise stated)

Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$V_{CEO(sus)*}$ Collector - Emitter Sustaining Voltage	$I_C = 200mA$	125			V
V_{EBO} Emitter – Base Voltage	$I_E = 50mA$	7			V
I_{CEO} Collector Cut-off Current	$V_{CE} = 100V$			1.5	mA
I_{CEX} Collector Cut-off Current	$V_{CE} = 160V$ $V_{BE} = -1.5V$			1.5	mA
	$T_C = 125^{\circ}C$			6	
I_{EBO} Emitter Cut-off Current	$I_C = 0$ $V_{EB} = 5V$			1	mA
$V_{CE(sat)*}$ Collector – Emitter Saturation Voltage	$I_C = 10A$ $I_B = 1A$		0.3	0.6	V
	$I_C = 20A$ $I_B = 2A$		0.7	1.2	
$V_{BE(sat)*}$ Base – Emitter Saturation Voltage	$I_C = 20A$ $I_B = 2A$		1.6	2	V
h_{FE*} DC Current Gain	$I_C = 10A$ $V_{CE} = 2V$	20		75	—
	$I_C = 20A$ $V_{CE} = 4V$	10			
$I_{S/b}$ Second Breakdown Collector Current	$V_{CE} = 30V$ $t = 1s$	5			A
	$V_{CE} = 140V$ $t = 1s$	1			
f_T Transition Frequency	$I_C = 1A$ $V_{CE} = 15V$ $f = 10MHz$	8			MHz

THERMAL CHARACTERISTICS

$R_{\theta JC}$ Thermal Resistance Junction to Case		1.17		$^{\circ}C/W$
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